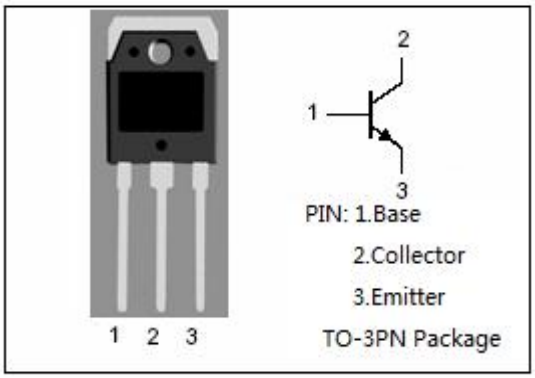
isc Silicon NPN Power Transistors — 2SD1065



DESCRIPTION

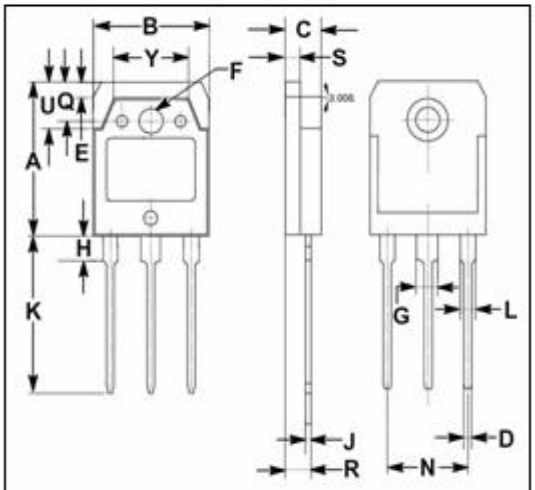
- Low Collector Saturation Voltage
  : $V_{CE(sat)}$= 0.4V(Max)@ I_C= 8A
- Wide Area of Safe Operation
- Complement to Type 2SB829
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Designed for relay drivers , high-speed inverters, converters,and other general high-current switching applications

ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	50	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current-Continuous	15	A
I_{CP}	Collector Current-Pulse	20	A
P_C	Collector Power Dissipation @ T_C=25℃	90	W
T_J	Junction Temperature	150	℃
T_{stg}	Storage Temperature Range	-55~150	℃



DIM	mm MIN	MAX
A	19.60	20.30
B	15.50	15.70
C	4.70	4.90
D	0.90	1.10
E	1.90	2.10
F	3.40	3.60
G	2.90	3.20
H	3.20	3.40
J	0.595	0.605
K	19.80	20.70
L	1.90	2.20
N	10.89	10.91
Q	4.90	5.10
R	3.35	3.45
S	1.995	2.100
U	5.90	6.20
Y	9.90	10.10

isc Silicon NPN Power Transistors 2SD1065

ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I_C= 1mA ; R_{BE}= ∞	50			V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	I_C= 1mA ; I_E= 0	60			V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I_E= 1mA ; I_C= 0	6			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	I_C= 8A; I_B= 0.4A			0.4	V
I_{CBO}	Collector Cutoff Current	V_{CB}= 40V; I_E= 0			100	μA
I_{EBO}	Emitter Cutoff Current	V_{EB}= 4V; I_C=0			100	μA
h_{FE-1}	DC Current Gain	I_C= 1A ; V_{CE}= 2V	70		280	
h_{FE-2}	DC Current Gain	I_C= 8A ; V_{CE}= 2V	30			
f_T	Current-Gain—Bandwidth Product	I_C= 1A ; V_{CE}= 5V		20		MHz
Switching times						
t_{on}	Turn-on Time	I_C= 2A; I_{B1}= I_{B2}= 0.2A R_L= 10Ω ;P_W=20 μs; V_{CC}= 20V		0.2		μs
t_{stg}	Storage Time			1.0		μs
t_f	Fall Time			0.1		μs

◆ **h_{FE-1} Classifications**

Q	R	S
70-140	100-200	140-280

NOTICE：

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.